NSN 5962-01-103-2005

Memory Microcircuit - Page 1 of 1

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Body Length: 0.785 inches **Body Width:** 0.310 inches **Body Height:** Between 0.130 inches and 0.180 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and programmable and 3-state output and w/enable **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -1.2 volts power source and 5.5 volts power source **Time Rating Per Chacteristic:** 65.00 nanoseconds propagation delay time, low to high level output Memory Device Type: Rom **Memory Capacity:** Unknown **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a Unit Of Measure: --**Demilitarization:** Yes - demil/mli Fiig: A458a0